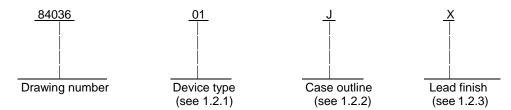
| | | | | | | | | п | EVISI | ONS | | | | | | | | | | |
|---|--|---|---------|---|---|--|---------------------|--------------|---------|----------------------------|-----------------------------|--|--|---|-------------------------------------|--|-----------------------|-------------------|----------|---------|
| LTR | | | | | D | ESCR | | N | | | | | DA | TE (YI | R-MO- | ·DA) | | APPF | ROVED |) |
| E | for de 16KX 09YX simila and 1 of su 6589 | Change to vendor similar part number for vendor CAGE number 61772 for devices 08KX, 09KX, 10KX, 11KX, 12KX, 13KX, 14KX, 15KX, and 16KX. Remove vendor CAGE number 61772 from devices 08YX, 09YX, 10YX, 11YX, 12YX, 13YX, 15YX, and 16YX. Change to vendor similar part number for vendor CAGE number 65786 for devices 09 and 11. Add vendor CAGE number 50088 to the drawing as a source of supply for devices 04JX and 05JX. Add vendor CAGE number 65896 to the drawing as a source of supply for devices 15 and 16. Removed 4.3.3 from drawing. Editorial changes throughout. | | | | | | | | and ndor 9 | 92-04-27 | | | | M. A. Frye | | | | | |
| F | Added provisions for the addition of QD certified parts to drawing. Updated boilerplate. Added CAGE OC7V7 as supplier ksr | | | | | | | | | 00-0 | 9-27 | | | Ray | mond | Monni | in | | | |
| G | Corre ksr | ection t | to mar | king pa | aragra | ph 3.5 | i. Up | dated | boilerp | olate p | aragra | iphs. | 05-0 |)3-11 | | | Ray | mond | Monni | in |
| CURRENT | | | | | | | | | | | | | | | | | | | | |
| REV SHEET | | | | | | | | | | | | | | | | | | | | |
| SHEET REV | G 15 | G 16 | G | G | G 19 | G 20 | G 21 | G 22 | | | | | | | | | | | | |
| SHEET | 15 | G 16 | | | 19 | G 20 | G 21 G | G 22 G | G | G | G | G | G | G | G | G | G | G | G | G |
| SHEET REV SHEET | 15 S | | G | G 18 RE\ | 19 | | 21 | 22 | G 3 | G 4 | G 5 | G 6 | G 7 | G 8 | G 9 | G 10 | G 11 | G 12 | G 13 | G 14 |
| SHEET REV SHEET REV STATU OF SHEETS PMIC N/A | 15 S | 16 | G | G 18 REV SHE PRE Ja | 19 V | 20 D BY | 21 G 1 | 22 G | | - | 5 | 6 EFEN | 7 SE SI | 8 UPPL | 9 .Y CE , OHI0 | 10 NTEF | 11 R COL 218-39 | 12 .UMB | 13 | - |
| SHEET REV SHEET REV STATU OF SHEETS PMIC N/A | 15 S NDAF | 16 RD CUIT | G | G 18 RE\ SHE PRE Ja CHE | 19 V EET PARE mes E | 20 ED BY Jami D BY | 21 G 1 | 22 G | | - | 5 | 6 EFEN | 7 SE SI | 8 UPPL | 9 .Y CE , OHI0 | 10 NTER 0 432 | 11 R COL 218-39 | 12 .UMB | 13 | _ |
| SHEET REV SHEET REV STATU OF SHEETS PMIC N/A | NDAF | 16 RD CUIT | G | G 18 REV SHE PRE Ja CHE Ra | 19 V EET Mes E ECKED | 20 D BY Jami D BY | 21 G 1 son | 22 G | | - | 5 | 6 EFEN | 7 SE SI | 8 UPPL | 9 .Y CE , OHI0 | 10 NTER 0 432 | 11 R COL 218-39 | 12 .UMB | 13 | _ |
| SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO DRA THIS D AVA FOR U | NDAF DCIRC AWIN | 16 RD CUIT G | G | G 18 RE\ SHE PRE Ja CHE Ra APF | 19 V EET Mes E CKED ay Mor | 20 ED BY Jami D BY Inin ED BY | 21 G 1 son | 22 G | | 4 MI DI | 5 DI CR GIT | 6 EFEN CC | 7 SE SI | 8 UPPL IBUS D://WV | 9 .Y СЕ , ОНИ vw.ds | 10 NTEFD 432 cc.dla ME 6K | 11 218-39 1.mil | 12 .UMB 990 | 13 US | _ |
| SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO DRA THIS D AVA FOR U | NDAF DCIRC AWIN RAWIN SE BY RTMEN NCIES | IG IS E ALL NTS OF TH | G 17 | G 18 RE\ SHE Ja CHE Ra APF Do | 19 V EET PARE CKEE ay Mor PROVI | 20 ED BY D BY Innin ED BY | 21 G 1 son | 22 G 2 | 3 | 4 MI DI (20 | 5 DI CR GIT 048 | 6 EFEN CC OC AL, X 8 | 7 SE SI DLUM http IRC | 8 UPPL IBUS 2://ww 2://ww IT S | 9 , ohio vw.ds S, 1 STA | 10 NTEF 0 432 cc.dla ME 6K TIC | 11 218-39 1.mil | 12 .UMB 990 | 13 US | _ |
| SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO DRA THIS D AVA FOR U DEPA AND AGEN DEPARTMEN | NDAF DCIRC AWIN RAWIN SE BY RTMEN NCIES | IG IS E ALL NTS OF TH DEFE | G 17 | G 18 RE\ SHE Ja CHE Ra CHE Ra DC | 19 V EET PARE CKEE ay Mor PROVI | 20 ED BY Jami D BY nnin ED BY 01 S APPI 84 – 0 I LEVE | 21 G 1 son | 22 G 2 | 3 | 4 MI DI (20 M(| 5 DI CR GIT 048 | G EFEN CC OC AL, X & DLI | 7 ISE SI DLUM http IRC , CI 3) B | BUPPL BUS D://WV CUIT MO IT S C S | 9 , ohio vw.ds S, 1 STA | 10 NTEF 0 432 cc.dla ME 6K TIC | 11 218-39 1 | 12 .UMB 990 | 13 US | _ |

.

1. SCOPE

1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 <u>Device type(s)</u>. The device type(s) identify the circuit function as follows:

| Device type 01 | <u>Generic number</u> <u>1</u> / | Supply voltage variation 10% | Address access time 200 ns (synchronous) |
|-------------------|----------------------------------|---------------------------------|---|
| 02 | | 10% | 90 ns |
| 03 | | 10% | 90 ns |
| 04 | | 10% | 150 ns |
| 05 | | 10% | 200 ns |
| 06 | | 10% | 70 ns |
| 07 | | 10% | 120 ns (synchronous) |
| 08 | | 10% | 45 ns |
| 09 | | 10% | 45 ns |
| 10 | | 10% | 55 ns |
| 11 | | 10% | 55 ns |
| 12 | | 10% | 70 ns |
| 13 | | 10% | 70 ns |
| 14 | | 10% | 35 ns |
| 15 | | 10% | 120 ns |
| 16 | | 10% | 90 ns |

1.2.2 <u>Case outline(s)</u>. The case outline(s) are as designated in MIL-STD-1835 and as follows:

| Outline letter | Descriptive designator | Terminals | Package style |
|----------------------------|--|----------------------------|--|
| J K L X Y Z | CDIP2-T24 or GDIP1-T24 CDFP3-F24 or GDFP2-F24 CDIP4-T24 or GDIP3-T24 CQCC1-N32 See Figure 1 CQCC1-N32 | 24 24 32 24 32 | dual-in-line package flat package dual-in-line package rectangular chip carrier package rectangular chip carrier package rectangular chip carrier package with castellated instead of chamfered corners and extended pad metallization at terminal number 1. |
| 3 | CQCC1-N28 | 28 | square chip carrier package |

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

1/ Generic numbers are listed on the standardized military drawing source approval bulletin at the end of this Standard Microcircuit Drawing and will also be listed in MIL-HDBK-103.

| STANDARD MICROCIRCUIT DRAWING | SIZE A | | 84036 |
|----------------------------------|-----------|----------------|-------|
| DEFENSE SUPPLY CENTER COLUMBUS | | REVISION LEVEL | SHEET |
| COLUMBUS, OHIO 43218-3990 | | G | 2 |

| 1.3 <u>Absolute maximum ratings</u>. Supply voltage range (V_{CC})0.3 V dc to +7.0 V dc <u>2</u>/ Temperature under bias55°C to +125°C Storage temperature range55°C to +150°C Maximum power dissipation (P_D) |
|--|
| Junction temperature (T _.)++150°C <u>3</u> / |
| All input or output voltages with respect to ground0.3 V dc to V_{cc} +0.3 V dc 4/ |
| 1.4 <u>Recommended operating conditions</u>. Case operating temperature range (T_C)55°C to +125°C Input low voltage (V_{IL}): Device types 01 through 160.3 V dc to 0.8 V dc 2/ |
| Input high voltage (V_{H}): |
| Device types 01, 072.4 V dc to VCC +0.3 V dc $2/$ Device types 02 through 06, 08 through 162.2 V dc to VCC +0.3 V dc $2/$ Supply voltage range (V _{CC}):4.5 V dc to 5.5 V dc $2/$ Minimum chip enable low time40 ns $5/$ Minimum chip enable high time40 ns $5/$ Maximum input rise time40 ns Maximum input fall time40 ns |

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

| MIL-STD-883 - | - | Test Method Standard Microcircuits. |
|----------------|---|--|
| MIL-STD-1835 - | - | Interface Standard Electronic Component Case Outlines. |

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings. MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <u>http://assist.daps.dla.mil/quicksearch/</u> or <u>http://assist.daps.dla.mil</u> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

- 3/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.
- 4/ Negative undershoots to a minimum of -3.0 V are allowed with a maximum of 20 ns pulse width.

5/ For device types 02, 03, and 06 only.

| STANDARD MICROCIRCUIT DRAWING | SIZE A | | 84036 |
|----------------------------------|-----------|----------------|-------|
| DEFENSE SUPPLY CENTER COLUMBUS | | REVISION LEVEL | SHEET |
| COLUMBUS, OHIO 43218-3990 | | G | 3 |

^{2/} All voltages referenced to V_{SS}.

3. REQUIREMENTS

3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used. This drawing has been modified to allow the manufacturer to use the alternate die/fabrication requirements of paragraph A.3.2.2 of MIL-PRF-38535 or alternative approved by the Qualifying Activity.

3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 <u>Case outline(s)</u>. The case outline(s) shall be in accordance with 1.2.2 herein and figure 1.

3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 2.

3.2.3 <u>Truth table(s)</u>. The truth table(s) shall be as specified on figure 3.

3.2.4 Logic diagram(s). The logic diagram(s) shall be as specified on figure 4.

3.2.5 <u>Die overcoat</u>. Polyimide and silicone coatings are allowable as an overcoat on the die for alpha particle protection only. Each coated microcircuit inspection lot (see inspection lot as defined in MIL-PRF-38535) shall be subjected to and pass the internal moisture content test at 5000 ppm (see method 1018 of MIL-STD-883). The frequency of the internal water vapor testing shall not be decreased unless approved by the preparing activity for class M. The TRB will ascertain the requirements as provided by MIL-PRF-38535 for classes Q and V. Samples may be pulled any time after seal.

3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked.

3.5.1 <u>Certification/compliance mark</u>. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, Appendix A. For Class Q product built in accordance with A.3.2.2 of MIL-PRF-38535 or other alternative approved by the Qualifying Activity, the "QD" certification mark shall be used in place of the "QML" or "Q" certification mark.

3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.

3.9 <u>Verification and review</u>. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

| STANDARD MICROCIRCUIT DRAWING | SIZE A | | 84036 |
|---|------------------|---------------------|----------------|
| DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 | | REVISION LEVEL G | SHEET 4 |

| | т | ABLE I. Electrical per | formance charac | teristics. | | | | |
|--------------------------------|-------------------|---|---------------------------|----------------------|-------------------------------------|-----------|---------|------|
| Test | Symbol | Test conditio V _{SS} = 0 V, 4.5 V -55°C ≤ T _C ≤ | ≤ V _{CC} ≤ 5.5 V | Group A subgroups | Device type | Lir | nits | Unit |
| | | unless otherwis | | | | Min | Max | - |
| High-level output voltage | VOH | I _{OH} = -1 mA | | 1,2,3 | 01-07, 15,16 | 2.4 | | V |
| | | I _{OH} = -4 mA | | 1,2,3 | 08-14 | | | |
| Low-level output voltage | V _{OL} | I _{OL} = +3.2 mA | | 100 | 01,07 | | 0.4 | V |
| | | I _{OL} = +4.0 mA | | 1,2,3 | 02,03, 06,15 | | 0.4 | , v |
| | | I _{OL} = +2.0 mA | | - | 04,05, | | | |
| | | | | - | 16 08-14 | | | |
| High impedance output | | I _{OL} = +8.0 mA | | | 01,02, | | | |
| leakage current | liolz | $\overline{OE} = V_{IH}$ | | 1,2,3 | 06,07 | -1.0 | 1.0 | μA |
| | IIOHZ | | | | 04,05, 09,11, 13,14, 15,16 | -10.0 | 10.0 | |
| | | | | 03,08, 10,12 | -5.0 | 5.0 | | |
| Input leakage current | IIL | V _{IN} = GND | | 1,2,3 | 01,02, 06,07 | -1.0 | 1.0 | μA |
| | ιг IIH | $V_{IN} = 5.5 V$ | | | 04,05, | -2.0 | 2.0 | |
| | | | | | 15 03,08, 10,12, 16 | -5.0 | 5.0 5.0 | - |
| | | | | | 09,11, 13,14 | -10.0 | 10.0 | - |
| Operating supply current | I _{CC1} | V _{CC} = 5.5 V, f = fma | v 3/ | 1,2,3 | 01,07 | | 10 | mA |
| | | $\overline{CE} = V_{IL}$, outputs o | pen | | 04,05, 13,15, 16 | | 90 | |
| | | All other inputs at V _I | L | | 02,03, 06 | | 70 | |
| | | | | | 08,10, 12 | | 85 | |
| | | | | | 09,11 | | 120 | |
| | | | | | 14 | | 150 | |
| See footnotes at end of table. | | | | | | | | |
| STAN MICROCIRCI | IDARD JIT DRAV | VING | SIZE A | | | | 84036 | |
| DEFENSE SUPPLY COLUMBUS, O | OLUMBUS | | REVISION L | evel G | SH | IEET 5 | | |

| | TABLE | I. Electrical performan | ce characteristics | <u>s</u> - Continued | | | | |
|---|-------------------|--|---------------------------------|----------------------|---------------------------|-----|-----------|------|
| Test | Symbol | Test condition V_{SS} = 0 V, 4.5 V \leq -55°C \leq T _C \leq | $\leq V_{CC} \leq 5.5 V$ subgro | Group A subgroups | Device type | Lir | nits | Unit |
| | | unless otherwise | | | | Min | Max | 1 |
| Standby supply current | I _{CC2} | $\overline{CE} = \overline{WE} = V_{IH}, I_O$ | = 0 | 1,2,3 | 02,03, 06 | | 8 | mA |
| | | | | | 04,05 | | 10 | _ |
| | | | | | 10,12, 15,16 | | 15 | |
| | | | | | 09,11, 13,14 | | 25 | |
| Standby supply current | I _{CC3} | $\overline{CE} = V_{CC} - 0.3 \text{ V}, \text{ I}_{C}$ |) = 0 | 1,2,3 | 06,07 | | 50 | |
| | | | | | 01,02 | | 100 | μΑ |
| | | | | | 04,05 | | 250 | |
| | | | | | 03,08, 10,12, 15,16 | | 900 | |
| | | | | | 13 | | 10 | mA |
| | | | | | 09,11, 14 | | 20 | |
| Data retention current | I _{CC4} | $\overline{CE} = V_{CC}, V_{CC} = 2$ | | 1,2,3 | 01,02 04,05 | | 50 100 | μA |
| | | | | | 08,10, 12,15, 16 | | 200 | |
| | | | | | 03 06,07 | | 300 25 | 1 |
| Input capacitance <u>4</u> / | CI | $V_I = V_{CC}$ or GND f = 1 MHz See 4.3.1c | | 4 | All | | 10 | pF |
| Output capacitance <u>4</u> / | CO | $V_I = V_{CC}$ or GND f = 1 MHz See 4.3.1c | | 4 | All | | 12 | pF |
| See footnotes at end of table. | | | | | | | | |
| | NDARD UIT DRAV | VING | SIZE A | | | | 840 | 36 |
| MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 | | | | REVISION L | EVEL G | SH | HEET | |

G

6

| | TA | BLE I. Electrical performance cha | racteristics | <u>s</u> - Con | tinued. | | | |
|----------------------------|---------------------|--|-----------------|----------------|------------------------|-----|------------|----------|
| Test | Symbol | Test conditions $\frac{1}{2}$ / V _{SS} = 0 V, 4.5 V \leq V _{CC} \leq 5.5 V -55°C \leq T _C \leq +125°C | Grou subgro | | Device type | L | Limits | |
| | | unless otherwise specified | | | | Min | Max | |
| Read/write cycle time | | _, _, | | | 01 | 280 | | - |
| une | t _{AVAV} | <u>5/</u> <u>6</u> / | 9, 10, | , 11 | 02,03,16 | 90 | | ns |
| | | | | | 04 | 150 | | - |
| | | | | | 05 | 200 | | |
| | | | | | 15 | 120 | | |
| | | | | | 07 | 170 | | |
| | | | | | 08,09 | 45 | | |
| | | | | | 10,11 | 55 | | |
| | | | | | 06,12,13 | 70 | | |
| | | | | | 14 | 35 | 000 | <u> </u> |
| Address access time | 1. | 5/ 6/ | 9, 10, | 11 | 01 | | 200 | |
| | t _{AVQV} | <u>5</u> / <u>6</u> / | 9, 10, | , 11 | 02,03,16 | | 90 150 | ns |
| | | | | | | | | |
| | | | | | 05 | | 200 120 | |
| | | | | | 07,15 08,09 | | 45 | |
| | | | | | 10,11 | | 45 55 | |
| | | | | | 06,12,13 | | 70 | |
| | | | | | 14 | | 35 | |
| Output hold after | | | | | 14 | 0 | | |
| address change <u>4</u> / | 4 | <u>5/</u> 6/ | 9, 10, | 11 | 04,05 | 10 | | ns |
| | t _{AVQX} | | 0, 10, 11 | | 02,03,06, 07,08-14 | 5 | | 115 |
| Output enable to output | | | | | 01,07 | 10 | | <u> </u> |
| active <u>4</u> / | tOLQX | <u>5/</u> 6/ | 9, 10, 11 | | 02,03,06, | 5 | | ns |
| | ULQA | | | | 08,12,13 | | | |
| | | | | | 04,05,09, 11,14,15, | 0 | | |
| | | | | | 16 | | | |
| Output enable access | | | | | 01,07,15 | | 80 | |
| time | tOLQV | <u>5/</u> <u>6</u> / | 9, 10, | , 11 | 02,03,16 | | 65 | ns |
| | | | | | 04 | | 60 | |
| | | | | | 05 | | 70 | 1 |
| | | | | | 08,09 | | 25 | 1 |
| | | | | | 10,11 | | 40 | 1 |
| | | | | | 06,12,13 | | 50 |] |
| | | | | | 14 | | 20 |] |
| See footnotes at end of ta | able. | | + | | • | | + | · |
| ST MICROCI | TANDARI RCUIT DI |) | IZE A | | | | 840 | 36 |
| DEFENSE SUPF COLUMBU | PLY CENTE | R COLUMBUS | | REVI | SION LEVEL G | | SHEET 7 | |
| DSCC FORM 2234 | | | | | | | | |

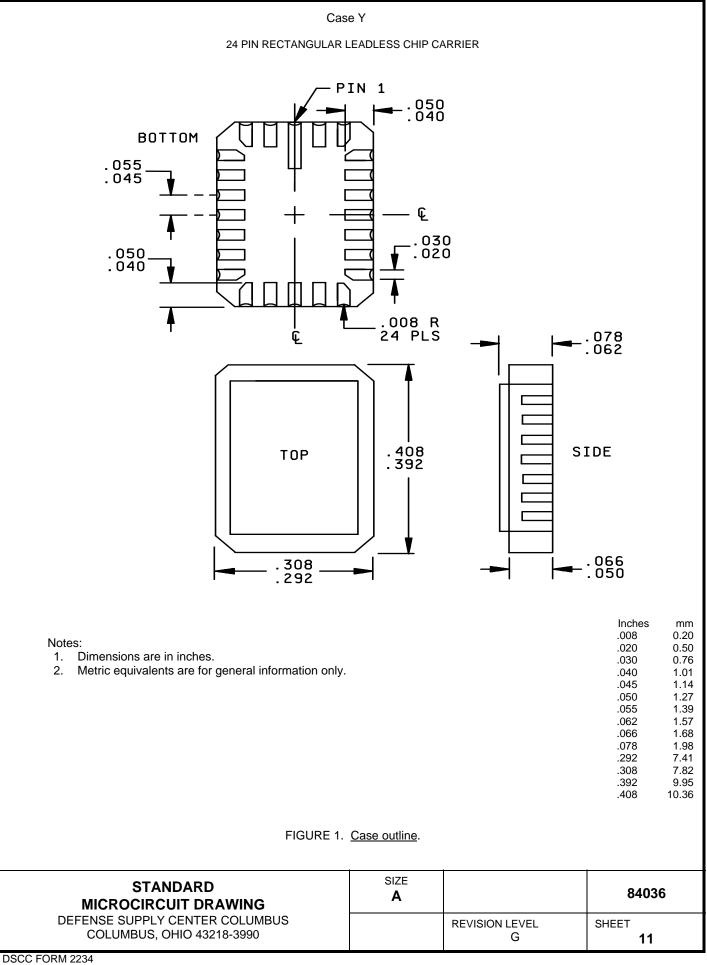
| | TA | BLE I. Electrical performat | nce chara | octeristics | <u>s</u> - Con | tinued. | | | |
|----------------------------|-------------------|---|------------|----------------|----------------|--------------------|-----------|---------|------------|
| Test | Symbol | Test conditions $\underline{1}/$ V _{SS} = 0 V, 4.5 V \leq V _{CC} \leq -55°C \leq T _C \leq +125° | 5.5 V C | Grou subgro | | Device type | | Limits | Unit |
| | | unless otherwise spec | cified | | | | Min | Max | |
| Chip enable to output | | | | | | 01,07 | 10 | | |
| active <u>4</u> / | t _{ELQX} | <u>5/</u> 6/ | | 9, 10, | , 11 | 02,03,06, | 5 | | ns |
| | | | | | | 08-14 | | | |
| | | | | | | 04,05,15, | 0 | | |
| | | | | | | 16 | | | |
| Chip enable access time | | | | | | 01 | | 200 | |
| ume | t _{ELQV} | <u>5/</u> 6/ | | 9, 10, | , 11 | 02,03,16 | | 90 | ns |
| | | | | | | 04 | | 150 | |
| | | | | | | 05 | | 200 | |
| | | | | | | 07,15 | | 120 | |
| | | | | | | 08,09 | | 45 | |
| | | | | | | 10,11 | | 55 | |
| | | | | | | 06,12,13 | | 70 | |
| | | | | | | 14 | | 35 | |
| Chip enable to output in | | | | | | 01 | | 80 | |
| high Z <u>4</u> / | ^t EHQZ | <u>5/ 6</u> / | | 9, 10, | , 11 | 02,03,07, 15,16 | | 50 | ns |
| | | | | | | 04,05 | | 60 | |
| | | | | | | 08,09 | | 25 | |
| | | | | | | 10,11 | | 30 | |
| | | | | | | 06,12,13 | | 35 | |
| | | | | | | 14 | | 15 | |
| Write recovery time | | | | | | 02,03,04, | 10 | | |
| | twha∨ | <u>5</u> / <u>6</u> / | | 9, 10, | , 11 | 05,06,15, 16 | | | ns |
| | | | | | | | 0 | | - |
| Chip enable to end-of- | | | | | | 09,11,14 01 | 200 | | |
| write | | <u>5/ 6</u> / | | 9, 10, | 11 | | 55 | | n 0 |
| | ^t ELWH | | | 3, 10, | , | 02,03,16 04 | | | ns |
| | | | | | | | 90 120 | | |
| | | | | | | 05,07 | | | |
| | | | | | | 06 | 45 | | - |
| | | | | | | 08,09,14 | 30 | | - |
| | | | | | | 10-13 | 40 | | |
| | | | | | | 15 | 70 | | |
| See footnotes at end of ta | ble. | | | | | | | | |
| ST MICROCIF | | | SIZ A | | | | | 8403 | 36 |
| DEFENSE SUPP COLUMBUS | LY CENTE | R COLUMBUS | | | REVI | SION LEVEL G | | SHEET 8 | |

| | ТА | BLE I. Electrical performat | nce charad | cteristics | <u>s</u> - Cont | tinued. | | | |
|-----------------------------------|---|---|------------|----------------|-----------------|--------------------|------------|------------|------|
| Test | Symbol | Test conditions $\underline{1}/V_{SS} = 0 \text{ V}, 4.5 \text{ V} \le V_{CC} \le -55^{\circ}\text{C} \le T_{C} \le +125^{\circ}$ | 5.5 V C | Grou subgro | | Device type | | Limits | Unit |
| | | unless otherwise spec | cified | | | | Min | Max | |
| Address valid to end-of- write | | 5/ 0/ | | | | 02,03, | 65 | | |
| WINC | ta∨wh | <u>5/</u> 6/ | | 9, 10, | , 11 | 12,13 | 400 | | ns |
| | | | | | | 04 05 | 100 130 | | _ |
| | | | | | | 15 | 105 | | - |
| | | | | | | 06 | 50 | | _ |
| | | | | | | 08,09,14 | 30 | | |
| | | | | | | 10,11 | 45 | | _ |
| | | | | | | 16 | 80 | | _ |
| Address to WE setup | | | | | | 02-06, | 10 | | |
| time | t _{A∨WL} | <u>5/6/</u> | | 9, 10, | , 11 | 15,16 | | | ns |
| | AVVL | | | | | 07,08,09, 11,14 | 0 | | _ |
| | | | | | | 10 | 5 | | |
| | | | | | | 12,13 | 15 | | _ |
| Address to CE setup time | tAVEL | <u>5/ 6</u> / | | 9, 10, | , 11 | 01,07 | 0 | | ns |
| Output enable to output | | | | | | 01 | | 80 | |
| in high Z <u>4</u> / | tohqz | <u>5/ 6</u> / | | 9, 10, | , 11 | 02,03,15, 16 | | 40 | ns |
| | | | | | | 04,07 | | 50 | |
| | | | | | | 05 | | 60 | |
| | | | | | | 08,09 | | 25 | |
| | | | | | | 10,11 | | 30 | |
| | | | | | | 06,12,13 | | 35 | |
| | | | | | | 14 | | 15 | |
| Write enable pulse | | | | | | 01 | 200 | | |
| width | twLwH | <u>5/</u> <u>6</u> / | | 9, 10, | , 11 | 02,03,16 | 55 | | ns |
| | | | | | | 04 | 90 | | |
| | | | | | | 05,07 | 120 | | _ |
| | | | | | | 15 | 70 | | _ |
| | | | | | | 08,11 | 25 | | |
| | | | | | | 06,10, | 40 | | |
| | | | | | | 12,13 09,14 | 20 | | _ |
| | | | | | | 09,14 | 20 | | |
| See footnotes at end of table. | | | | | | | | | |
| | | | SIZ A | | | | | 840 | 36 |
| DEFENSE SUPF | MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 | | | | REVIS | SION LEVEL G | | SHEET 9 | |

| Test | Symbol | Test conditions $1/2/$ V _{SS} = 0 V, 4.5 V \leq V _{CC} \leq 5.5 V -55°C \leq T _C \leq +125°C | Group A subgroups | Device type | Limits | | Unit |
|--|-------------------|---|----------------------|-----------------------|----------|-----|------|
| | | unless otherwise specified | | | Min | Max | |
| Data setup to end-of- | | | | 01 | 80 | | |
| write | tD∨WH | <u>5/ 6</u> / | 9, 10, 11 | 02,03,06, 12,13,16 | 30 | | ns |
| | | | | 04,07 | 50 | | |
| | | | | 05 | 70 | | |
| | | | | 08,09 | 20 | | |
| | | | | 10,11 | 25 | | |
| | | | | 15 | 35 | | |
| | | | | 14 | 15 | | |
| Data hold after end-of- | | | | 01,06,07 | 10 | | |
| write | twhdx | <u>5/ 6</u> / | 9, 10, 11 | 02,03,04, 05,15,16 | 15 | | ns |
| | | | | 08,09,11, 14 | 0 | | |
| | | | | 10,12,13 | 5 | | |
| N | | | | 01 | 80 | | |
| Minimum chip-enable high time after write | ^t EHEL | <u>5/ 6</u> / | 9, 10, 11 | 07 | 50 | | ns |
| Address hold time after | | <u>5/ 6</u> / | 9, 10, 11 | 01 | 50 30 | | |
| CE low | ^t ELAX | | 9, 10, 11 | 07 | | | ns |
| | | | | 01 | 200 | | |
| Chip-enable pulse width during write | t _{ELEH} | <u>5/ 6</u> / | 9, 10, 11 | 07 | 120 | | ns |
| Write enable pulse | | | | 01 | 200 | | |
| setup time | tWLEH | <u>5/</u> <u>6</u> / | 9, 10, 11 | 02,03,16 | 55 | | ns |
| | | | | 04 | 90 | | |
| | | | | 05,07 | 120 | | |
| | | | | 08 | 30 | | |
| | | | | 06,10, | 40 | | |
| | | | | 12,13 | | | |
| | | | | 09,14 | 20 | | |
| | | | | 11 | 25 | | |
| | | | | 15 | 70 | | |

5/ AC measurements assume transition time ≤ 5 ns and input levels are from V_{SS} to 3.0 V. Output load is specified on figure 5. Reference timing levels are at 1.5 V. 6/ For timing waveforms, see figure 6.

SIZE STANDARD 84036 Α **MICROCIRCUIT DRAWING** DEFENSE SUPPLY CENTER COLUMBUS SHEET **REVISION LEVEL** COLUMBUS, OHIO 43218-3990 G 10



| Device Types | | | All | | |
|---|---|---|--|---|--|
| Case Outlines | X and Z | Y, J, K | , and L | | 3 |
| Terminal Number 1 2 3 4 5 6 7 8 9 10 11 12 33 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 29 30 31 32 | Terminal Symbol NC NC NC A7 A6 A5 A4 A3 A2 A1 A0 NC DQ0, I/O0 DQ1, I/O1 DQ2, I/O2 Vss NC DQ3, I/O3 DQ4, I/O4 DQ5, I/O5 DQ6, I/O6 DQ7, I/O7 CE, E A10 OE, G WE, W NC A9 A8 NC NC NC NC NC NC NC NC NC A8 NC NC </th <th>Terminal Number 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 </th> <th>Terminal Symbol A7 A6 A5 A4 A3 A2 A1 A0 DQ0, I/O0 DQ1, I/O1 DQ2, I/O2 V_{SS} DQ3, I/O3 DQ4, I/O4 DQ5, I/O5 DQ6, I/O6 DQ7, I/O7 CE, E A10 OE, G WE, W A9 A8 V_{CC}</th> <th>Terminal Number 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 </th> <th>Terminal Symbol A7 A6 A5 A4 A3 A2 NC NC A1 A0 DQ1, I/O1 DQ2, I/O2 DQ3, I/O3 V_{SS} DQ4, I/O4 DQ5, I/O5 DQ6, I/O6 DQ7, I/O7 DQ8, I/O8 <u>CE</u>, <u>E</u> NC NC A10 <u>OE</u>, <u>G</u> WE, W A9 A8 V_{CC}</th> | Terminal Number 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 | Terminal Symbol A7 A6 A5 A4 A3 A2 A1 A0 DQ0, I/O0 DQ1, I/O1 DQ2, I/O2 V _{SS} DQ3, I/O3 DQ4, I/O4 DQ5, I/O5 DQ6, I/O6 DQ7, I/O7 CE, E A10 OE, G WE, W A9 A8 V _{CC} | Terminal Number 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 | Terminal Symbol A7 A6 A5 A4 A3 A2 NC NC A1 A0 DQ1, I/O1 DQ2, I/O2 DQ3, I/O3 V _{SS} DQ4, I/O4 DQ5, I/O5 DQ6, I/O6 DQ7, I/O7 DQ8, I/O8 <u>CE</u> , <u>E</u> NC NC A10 <u>OE</u> , <u>G</u> WE, W A9 A8 V _{CC} |

FIGURE 2. Terminal connections.

| STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 | SIZE A | | 84036 |
|---|-----------|---------------------|-------------|
| | | REVISION LEVEL G | SHEET 12 |

Device types 01 and 07

Read cycle

| Time | | | Inputs | | | |
|-----------|-----|----|--------|---|----|---|
| reference | | | | | | Function |
| | CE | WE | ŌĒ | А | DQ | |
| -1 | Н | Х | Х | Х | Z | Memory disabled |
| 0 | Ψ | Н | Х | V | Z | Cycle begins, addresses are latched |
| 1 | L | Н | L | Х | Х | Output enabled |
| 2 | L | Н | L | Х | V | Output valid |
| 3 | [1] | Н | Х | Х | V | Read accomplished |
| 4 | Н | Х | Х | Х | Z | Prepare for next cycle (same as –1) |
| 5 | Ψ | Н | Х | V | Z | Cycle ends, next cycle begins (same as 0) |

Write cycle

| Time | | | Inputs | | | |
|-----------|-----|-----|--------|---|----|---|
| reference | | | | | | Function |
| | CE | WE | OE | A | DQ | |
| -1 | Н | Х | Н | Х | Х | Memory disabled |
| 0 | Ψ | Х | Н | V | Х | Cycle begins, addresses are latched |
| 1 | L | L | Н | Х | Х | Write period begins |
| 2 | L | [1] | Н | Х | V | Data is written |
| 3 | [1] | Н | Н | Х | Х | Write completed |
| 4 | Н | Х | Н | Х | Х | Prepare for next cycle (same as -1) |
| 5 | Ψ | Х | Н | V | Х | Cycle ends, next cycle begins (same as 0) |

Device types 02 - 06 and 08 - 16

| CE | ŌĒ | WE | Mode | DQ |
|-----|-----|-----|----------|-----------------|
| VIH | Х | Х | Deselect | High Z |
| VIL | Х | VIL | Write | D _{IN} |
| VIL | VIL | VIH | Read | DOUT |
| VIL | VIH | VIH | Read | High Z |

X = Don't care

H = HIGH

L = LOW

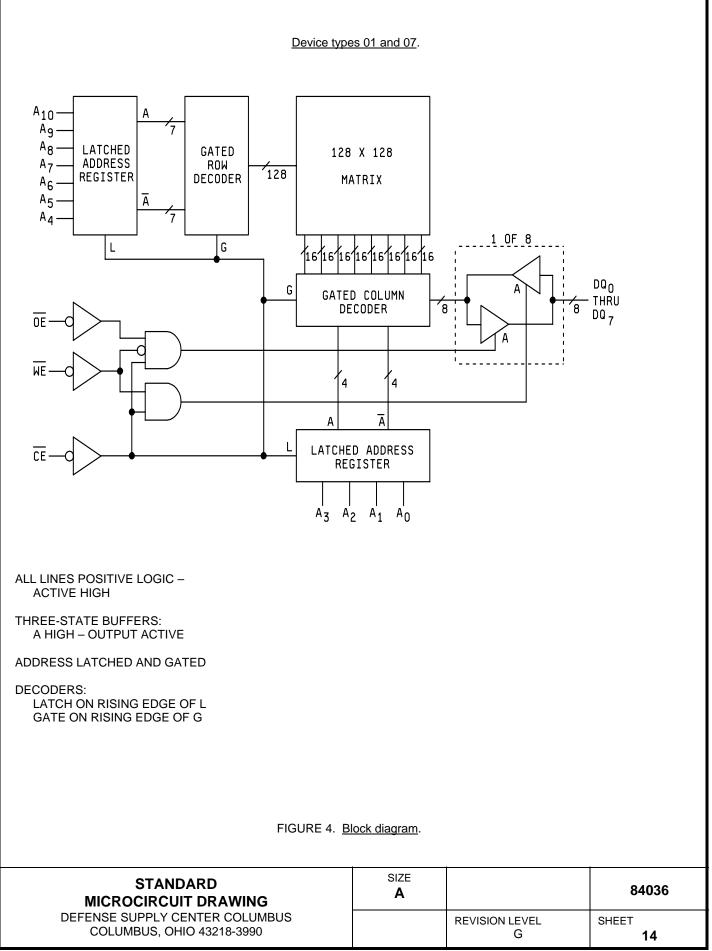
V = VALID

 $\Psi = \mathsf{TRANSITION} \ \mathsf{HIGH} \ \mathsf{TO} \ \mathsf{LOW}$

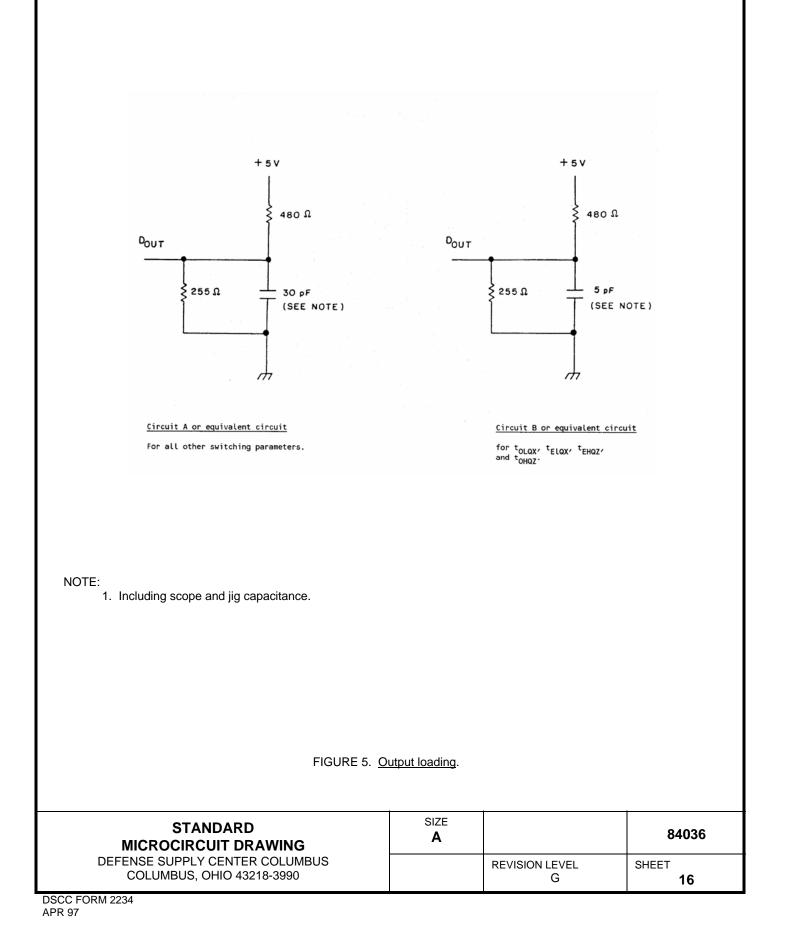
 Ξ = TRANSITION LOW TO HIGH

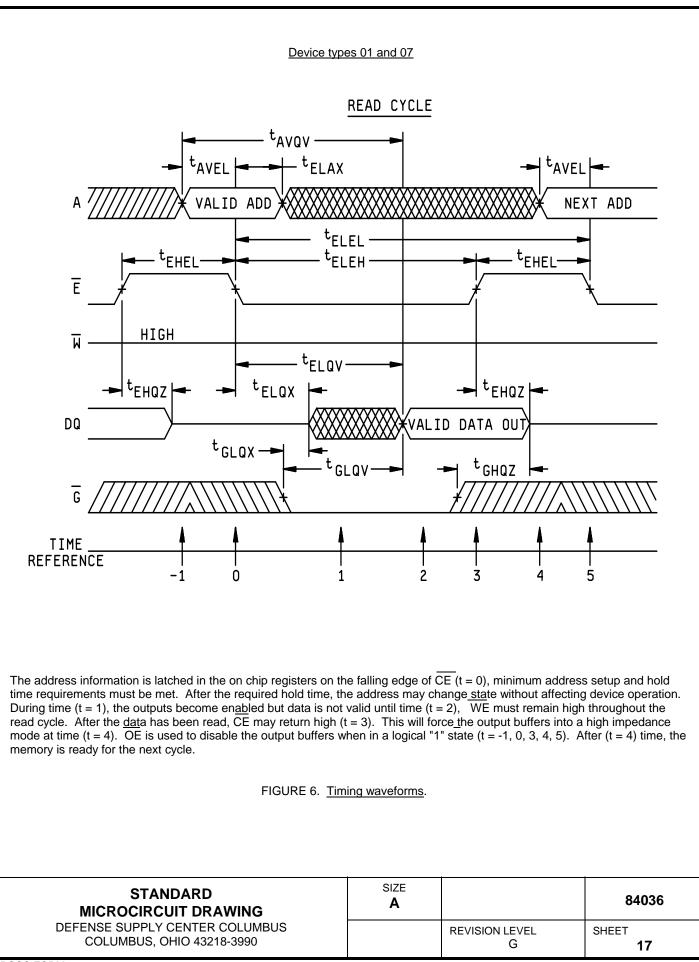
FIGURE 3. Truth table.

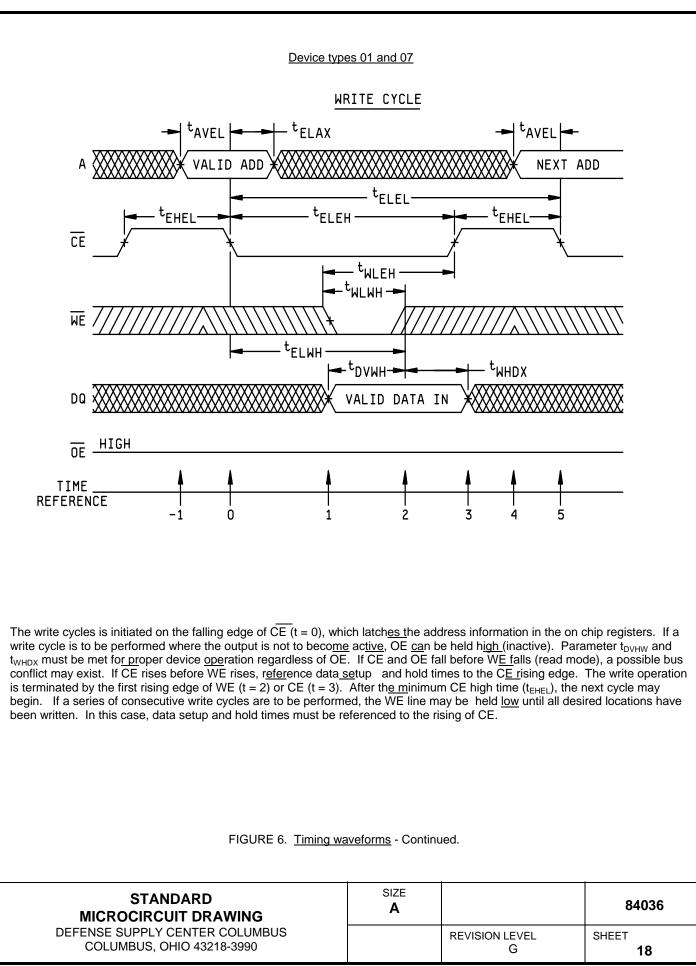
| STANDARD MICROCIRCUIT DRAWING | SIZE A | | 84036 |
|----------------------------------|-----------|----------------|-------|
| DEFENSE SUPPLY CENTER COLUMBUS | | REVISION LEVEL | SHEET |
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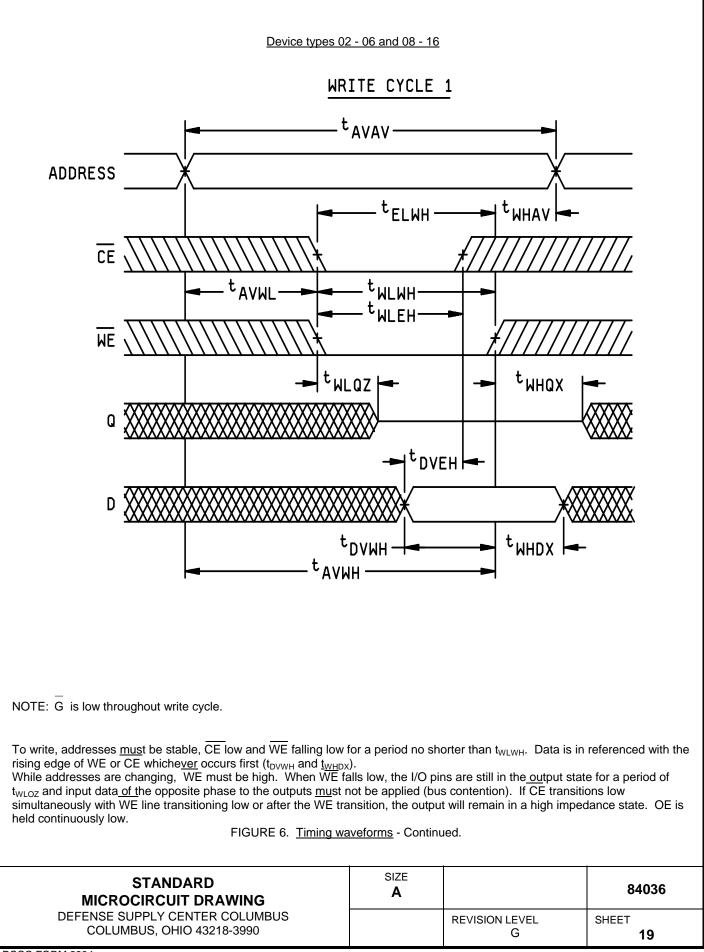


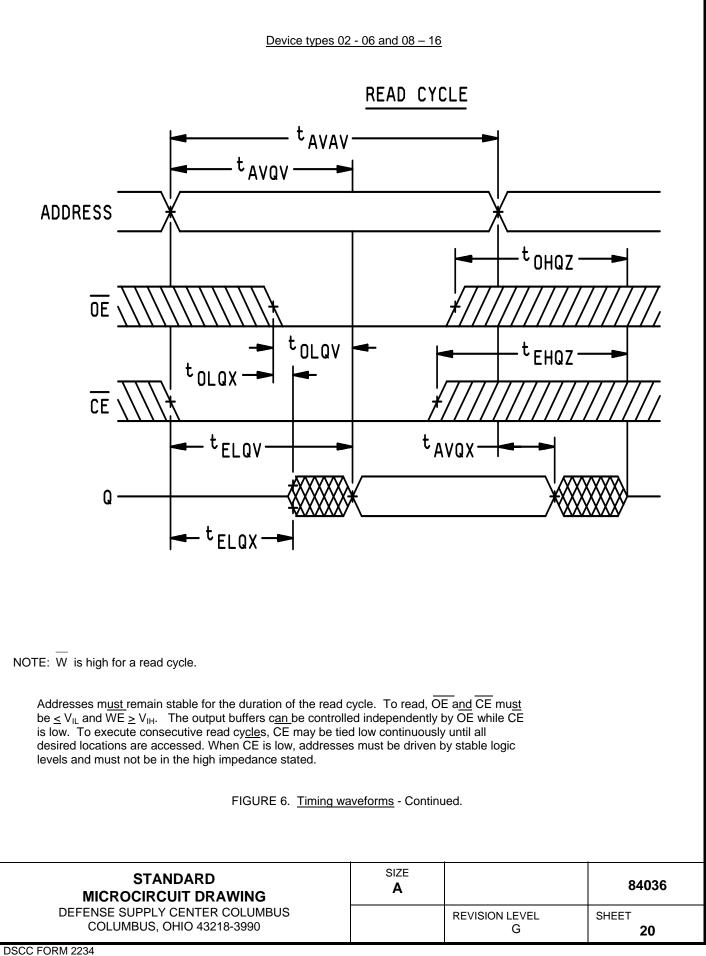
Device types 02 - 06 and 08 - 16 A₁ -А A₂ – A3 — ROW ADDRESS 128 X 128 MEMORY ARRAY ROW A4-DECODER 128 BUFFER A₅-A₆-Ā Α7 7 1 OF 8 DQ_O Thru DQ₇ 128 8 COLUMN DECODER AND DATA INPUT OUTPUT 8 Ā Ē 14 4 Α COLUMN ADDRESS BUFFER G W Α8 A₀ Ag A₁₀ FIGURE 4. Block diagram - Continued. SIZE **STANDARD** 84036 Α **MICROCIRCUIT DRAWING** DEFENSE SUPPLY CENTER COLUMBUS SHEET **REVISION LEVEL** COLUMBUS, OHIO 43218-3990 G 15











4. VERIFICATION

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $TA = +125^{\circ}C$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

| MIL-STD-883 test requirements | Subgroups (in accordance with MIL-STD-883, method 5005, table I) |
|--|---|
| Interim electrical parameters (method 5004) | |
| Final electrical test parameters (method 5004) | 1*, 2, 3, 7, 8A, 8B, 9, 10, 11 |
| Group A test requirements (method 5005) | 1, 2, 3, 4, 7, 8A, 8B, 9, 10, 11 |
| Groups C and D end-point electrical parameters (method 5005) | 1, 7, 9 |

TABLE II. Electrical test requirements.

* PDA applies to subgroup 1.

4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_I and C_O measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance. Sample size is five (5) devices with no failures, and all input and output terminals tested.
- d. Subgroups 7, 8A and 8B shall include verification of the truth table.

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|---|-----------|---------------------|-------------|
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4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $TA = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.

6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

| STANDARD MICROCIRCUIT DRAWING | SIZE A | | 84036 |
|----------------------------------|-----------|----------------|-------|
| DEFENSE SUPPLY CENTER COLUMBUS | | REVISION LEVEL | SHEET |
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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 05-03-11

Approved sources of supply for SMD 84036 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revisions of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

| Standard microcircuit drawing PIN <u>1</u> / | Vendor CAGE number | Vendor similar PIN <u>2</u> / |
|---|--------------------------|-------------------------------------|
| 8403601JA | <u>3</u> / | HM1-6516/883 |
| 8403601ZA | <u>3</u> / | HM1-6516/883 |
| 8403602JA | 34371 | HM1-65162/883 |
| 8403602ZA <u>4</u> / | 34371 | HM1-65162/883 |
| 8403603JA <u>4</u> / | 34371 | HM1-65162C/883 |
| 8403603ZA | <u>3</u> / | HM1-65162C/883 |
| 8403604JA | <u>3</u> / <u>3</u> / | MKB6116P-82 SMJ5517-15JDM |
| 8403604ZA | <u>3</u> / | SMJ5517-15FGM |
| 8403605JA | <u>3</u> / <u>3</u> / | MKB6116P-83 SMJ5517-20JDM |
| 8403605ZA | <u>3</u> / | SMJ5517-20FGM |
| 8403606JA | 34371 | HM1-65162B/883 |
| 8403606ZA | <u>3</u> / | HM1-65162B/883 |
| 8403607JA | <u>3</u> / | HM1-6516B/883 |
| 8403607ZA | <u>3</u> / | HM1-6516B/883 |
| 8403608JA | 61772 | IDT6116LA45DB |
| 8403608XA | <u>3</u> / | IDT6116LA45L32B |
| 8403608LA | 61772 | IDT6116LA45TDB |
| 8403608KA | <u>3</u> / | IDT6116LA45EB |
| 84036083A | <u>3</u> / | IDT6116LA45L28B |
| 8403608YA | <u>3</u> / | IDT6116LA45L24B |

STANDARD MICROCIRCUIT DRAWING BULLETIN - Continued

| | Т | T |
|---|---|--|
| Standard microcircuit drawing PIN <u>1</u> / | Vendor CAGE number | Vendor similar PIN 2/ |
| 8403609JA | 61772 0C7V7 <u>3/</u> | IDT6116SA45DB QP6116A-45DMB CY6116A-45DMB |
| 8403609XA | 0C7V7 <u>3/</u> <u>3/</u> | QP6117A-45LMB IDT6116SA45L32B CY6117A-45LMB |
| 8403609LA | 0C7V7 <u>3/</u> 61772 <u>3/</u> 3DTT2 | QP7C128A-45DMB SMJ68CE16S-45JDM IDT6116SA45TDB CY7C128A-45DMB P4C116-45DMB |
| 8403609KA | 0C7V7 <u>3/</u> <u>3/</u> 3DTT2 | QP7C128A-45KMB IDT6116SA45EB CY7C128-45KMB P4C116-45FMB |
| 84036093A | 0C7V7 <u>3/</u> <u>3/</u> 3DTT2 | QP6116A-45LMB IDT6116SA45L28B CY6116A-45LMB P4C116-45L28MB |
| 8403609YA | 0C7V7 <u>3/</u> 3DTT2 | QP7C128A-45LMB IDT6116SA45L24B CY7C128A-45LMB P4C116-45LMB |
| 8403610JA | 61772 | IDT6116LA55DB |
| 8403610XA | <u>3/</u> 0C7V7 | IDT6116LA55L32B 6116-55/XA |
| 8403610LA | 61772 | IDT6116LA55TDB |
| 8403610KA | <u>3/</u> 0C7V7 | IDT6116LA55EB 6116-55/KA |
| 84036103A | <u>3/</u> 0C7V7 | IDT6116LA55L28B 6116-55/3A |
| 8403610YA | <u>3/</u> 0C7V7 | IDT6116LA55L24B 6116-55/YA |
| 8403611JA | 0C7V7 61772 <u>3</u> / | QP6116A-55DMB IDT6116SA55DB CY6116A-55DMB |
| 8403611XA | 0C7V7 <u>3</u> / <u>3</u> / | QP6117A-55LMB IDT6116SA55L32B CY6117A-55LMB |
| 8403611LA | 0C7V7 <u>3</u> / 61772 <u>3</u> / 3DTT2 | QP7C128A-55DMB SMJ68CE16S-55JDM IDT6116SA55TDB CY7C128A-55DMB P4C116-55DMB |

STANDARD MICROCIRCUIT DRAWING BULLETIN - Continued

| Standard microcircuit drawing PIN <u>1</u> / | Vendor CAGE number | Vendor similar PIN <u>2</u> / |
|---|---|--|
| 8403611KA | 0C7V7 <u>3/</u> <u>3/</u> 3DTT2 | QP7C128A-55KMB IDT6116SA55EB CY7C128-55KMB P4C116-55FMB |
| 84036113A | 0C7V7 <u>3/</u> <u>3/</u> 3DTT2 | QP6116A-55LMB IDT6116SA55L28B CY6116A-55LMB P4C116-55L28MB |
| 8403611YA | 0C7V7 <u>3/</u> <u>3/</u> 3DTT2 | QP7C128A-55LMB IDT6116SA55L24B CY7C128A-55LMB P4C116-55LMB |
| 8403612JA | 61772 | IDT6116LA70DB |
| 8403612XA | <u>3</u> / | IDT6116LA70L32B |
| 8403612LA | 61772 | IDT6116LA70TDB |
| 8403612KA | <u>3</u> / | IDT6116LA70EB |
| 84036123A | <u>3</u> / | IDT6116LA70L28B |
| 8403612YA | <u>3</u> / | IDT6116LA70L24B |
| 8403613JA | 61772 | IDT6116SA70DB |
| 8403613XA | <u>3</u> / | IDT6116SA70L32B |
| 8403613LA | 61772 | IDT6116SA70TDB |
| 8403613KA | <u>3</u> / | IDT6116SA70EB |
| 84036133A | <u>3</u> / | IDT6116SA70L28B |
| 8403613YA | <u>3</u> / | IDT6116SA70L24B |
| 8403614JA | 0C7V7 <u>3</u> / | QP6116A-35DMB CY6116A-35DMB |
| 8403614XA | 0C7V7 <u>3</u> / | QP6117A-35LMB CY6117A-35LMB |
| 8403614LA | 0C7V7 <u>3/</u> <u>3</u> / 3DTT2 | QP7C128A-35DMB SMJ68CE16S-35JDM CY7C128A-35DMB P4C116-35DMB |
| 8403614KA | 0C7V7 <u>3</u> / 3DTT2 | QP7C128A-35KMB CY7C128A-35KMB P4C116-35FMB |

STANDARD MICROCIRCUIT DRAWING BULLETIN - Continued

| Standard microcircuit drawing PIN <u>1</u> / | Vendor CAGE number | Vendor similar PIN <u>2</u> / |
|---|-----------------------------------|--|
| 84036143A | 0C7V7 <u>3</u> / 3DTT2 | QP6116A-35LMB CY6116A-35LMB P4C116-35L28MB |
| 8403614YA | 0C7V7 <u>3</u> / 3DTT2 | QP7C128A-35LMB CY7C128A-35LMB P4C116-35LMB |
| 8403615JA | <u>3</u> / 61772 | L6116HMB120 IDT6116LA120DB |
| 8403615XA | <u>3</u> / <u>3</u> / 0C7V7 | L6116TMB120 IDT6116LA120L32B 6116-120/XA |
| 8403615LA | <u>3</u> / 61772 | L6116CMB120 IDT6116LA120TDB |
| 8403615KA | <u>3/</u> <u>3</u> / 0C7V7 | L6116FMB120 IDT6116LA120EB 6116-120/KA |
| 84036153A | <u>3</u> / <u>3</u> / 0C7V7 | L6116KMB120 IDT6116LA120L28B 6116-120/3A |
| 8403615YA | <u>3/</u> <u>3</u> / 0C7V7 | L6116TMB IDT6116LA120L24B 6116-120/YA |
| 8403616JA | <u>3</u> / 61772 | L6116HMB90 IDT6116LA90DB |
| 8403616XA | <u>3</u> / <u>3</u> / | L6116TMB90 IDT6116LA90L32B |
| 8403616LA | <u>3</u> / 61772 | L6116CMB90 IDT6116LA90TDB |
| 8403616KA | <u>3</u> / <u>3</u> / | L6116FMB90 IDT6116LA90EB |
| 84036163A | <u>3</u> / <u>3</u> / | L6116KMB90 IDT6116LA90L28B |
| 8403616YA | <u>3</u> / <u>3</u> / | L6116TMB IDT6116LA120L24B |

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.

- <u>2</u>/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- $\underline{3}$ / Not available from an approved source.
- $\frac{1}{4}$ Vendor has indicated an end-of-life date of 10/5/04 for this device.

| Vendor CAGE number | Vendor name and address |
|-----------------------|--|
| 34371 | Intersil Corporation 2401 Palm Bay Blvd PO Box 883 Melbourne, FL 32902-0883 |
| 61772 | Integrated Device Technology 2975 Stender Way Santa Clara, CA 95054 |
| 3DTT2 | Pyramid Semiconductor Corporation 1340 Bordeaux Drive Sunnyvale, CA 94089 |
| 0C7V7 | QP Semiconductor 2945 Oakmead Village Court Santa Clara, CA 95051 |

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